TOSHIBA Transistor Silicon NPN Triple Diffused Type

2SC5458

High Voltage Switching Applications Switching Regulator Applications DC-DC Converter Applications DC-AC Inverter Applications

• Excellent switching times: $t_r = 0.5 \mu s \text{ (max)}$

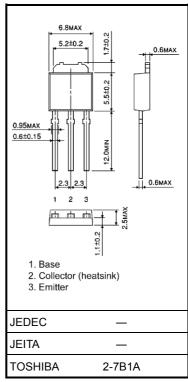
 $t_f = 0.3 \ \mu s \ (max) \ (IC = 0.4 \ A)$

• High collector breakdown voltage: VCEO = 400 V

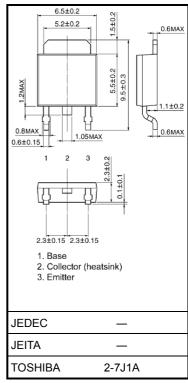
Maximum Ratings (Ta = 25°C)

Characteristics		Symbol	Rating	Unit	
Collector-base voltage		V _{CBO}	600	V	
Collector-emitter voltage		V _{CEO}	400	V	
Emitter-base voltage		V _{EBO}	7	V	
Collector current	DC	I _C	0.8	А	
	Pulse	I _{CP}	1.5		
Base current		Ι _Β	0.5	Α	
Collector power dissipation	Ta = 25°C	Pc	1.0	W	
	Tc = 25°C	FC	10		
Junction temperature		Tj	150	°C	
Storage temperature range		T _{stg}	-55 to 150	°C	

Unit: mm



Weight: 0.36 g (typ.)



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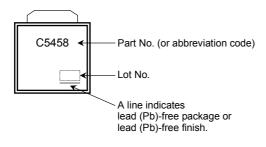


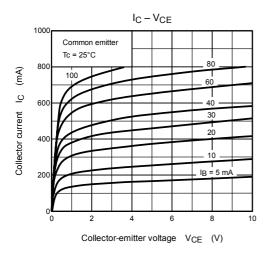
Electrical Characteristics (Ta = 25°C)

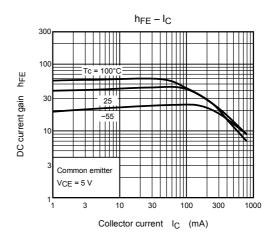
Characteristics		Symbol	Test Condition	Min	Тур.	Max	Unit
Collector cut-off c	urrent	I _{CBO}	V _{CB} = 480 V, I _E = 0	_	_	100	μΑ
Emitter cut-off cui	rent	I _{EBO}	V _{EB} = 7 V, I _C = 0	_	_	100	μA
Collector-base breakdown voltage		V _(BR) CBO	I _C = 1 mA, I _E = 0	600	_	_	V
Collector-emitter	oreakdown voltage	V (BR) CEO	I _C = 10 mA, I _B = 0	400	_	_	V
DC current gain		h _{FE}	V _{CE} = 5 V, I _C = 1 mA	20	_	_	
			V _{CE} = 5 V, I _C = 0.1 A	30	_	80	
Collector emitter	saturation voltage	V _{CE (sat)}	I _C = 0.3 A, I _B = 0.04 A		_	1.0	٧
Base-emitter saturation voltage		V _{BE} (sat)	I _C = 0.3 A, I _B = 0.04 A	_	_	1.3	٧
Switching time Storage	Turn-on time	t _r	20 μs	_	_	0.5	μs
	Storage time	t _{stg}		_	_	2.0	
	Fall time	t _f	I_{B1} = 50 mA, I_{B2} = -100 mA DUTY CYCLE ≤ 1%	_	_	0.3	

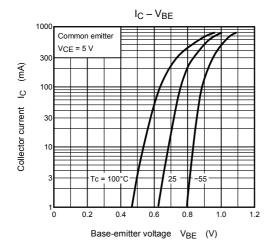
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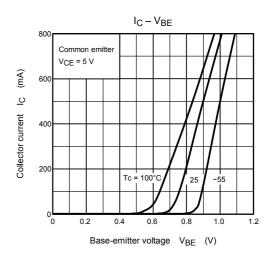
Marking

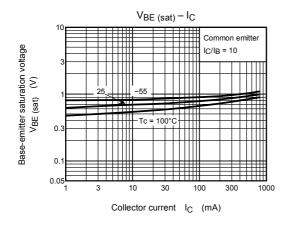


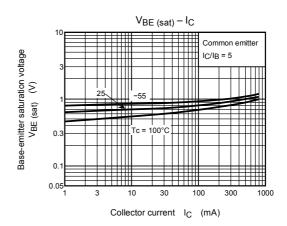




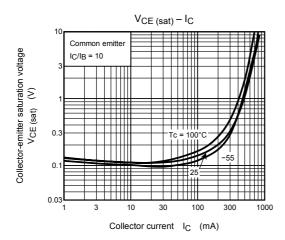


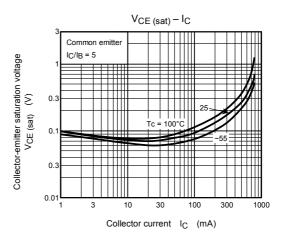


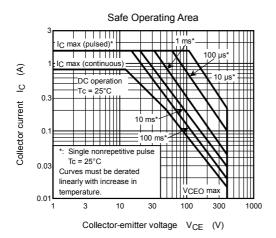




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Handbook" etc..

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